NSN 5961-00-252-1330

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-252-1330 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.340 inches Overall Diameter: 0.620 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 55.0 breakdown voltage, collector-to-base, emitter open and 3.5 breakdown voltage, emitter-to-base, collector open and 40.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 108.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 uninsulated wire lead **Specification Data:** 80131-release5388 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** Demilitarization: